NSN 5961-01-005-2985

Transistor - Page 1 of 2



View Online at https://aerobasegroup.com/nsn/5961-01-005-2985 **Inclosure Material:** Metal **Overall Length:** 1.252 inches **Overall Height:** 0.295 inches **Overall Width:** 0.700 inches **Function For Which Designed:** Amplifier **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 250.0 collector to base voltage/static/emitter open and 175.0 collector to emitter voltage/static/base open and 6.0 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** 5.00 amperes source cutoff current and 1.00 amperes source cutoff current **Power Rating Per Characteristic:** 35.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 1 case and 2 pin **Specification Data:**

N/a

Shelf Life:

Unit Of Measure:

80131-release 6504 professional/industrial association specification

NSN 5961-01-005-2985

Transistor - Page 2 of 2



Demilitarization:

No

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